APPLICATION NOTE

Contactless Angle Measurement using KMZ41 and UZZ9001

AN00004

Philips Semiconductors





Abstract

Angle measurement is frequently required in both automotive and industrial applications. Contactless methods have the advantage that they are free of wear. If a magnetic field acts as the transmitter between the physical value to be measured and the actual sensor, the magnetic system and the signal conditioning electronics can be encapsulated separately making such systems robust against dirt, dust and liquid as well as mechanical destruction. Among this class of measurement systems, those using the magnetic field and not the field strength. Therefore MR based systems tolerate variations in field strength caused by ageing or temperature-sensitivity of the magnet as well as mechanical tolerances. This recommends MR based systems for applications where robust, precise, and also cost-efficient solutions are required.

Philips Semiconductors provides a two-chip solution for an application-specific MR angle measurement system. It consists of the magnetoresistive sensor KMZ41 and the sensor signal conditioning IC UZZ9000 or UZZ9001. The UZZ9000 is described in the Application Note AN98097 from Philips Semiconductors. This Application Note deals with the UZZ9001 only. Both ICs were designed for the usage with the KMZ41 and therefore provide an optimised interface to this sensor. But nevertheless, they can also be used in conjunction with other sensors providing two sinusoidal output signals with a 90°-phase shift.

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Contactless Angle Measurement using KMZ41 and UZZ9001

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Summary

This report describes how to build a MR based measurement system using the magnetoresistive sensor KMZ41 and the sensor signal conditioning IC UZZ9001 available from Philips Semiconductors. The UZZ9001 is very similar to the UZZ9000 described in the Application note AN98097. Instead of the analog signal output, the UZZ9001 provides an SPI (serial digital) interface to the application. Moreover, the UZZ9001 operates in 180° mode only and provides no possibility to adjust the mechanical offset.

The first section gives an introduction into MR technology. It is shown that the magnetoresistive effect is naturally an angular effect recommending its use for angle measurement applications. The next sections describe the basic function of a system consisting of the sensor KMZ41 and the sensor signal conditioning IC UZZ9001. The KMZ41 sensor comprises two Wheatstone bridges on one substrate. This gives a very good matching of mechanical and electrical properties. The signal conditioning IC UZZ9001 is optimised for the usage with the KMZ41 but can also be used in conjunction with any other sensor providing two sinusoidal signals with 90°-phase shift, such as resolver applications, Hall sensors and GMR sensors. This mixed signal IC provides a serial digital output from which the angle information can be read digitally with 13-bit resolution. Both KMZ41 and UZZ9001 are specified between -40°C to +150°C for normal operation.

The last section describes the non-ideal cases and their impact on system accuracy. The error analysis based on a 3-Sigma confidence interval shows that the absolute accuracy is better than 0.6° in a temperature range from - 40°C to +85°C. This corresponds to an relative error better than 0.4% referred to 180° full scale. At 150°C, the maximum absolute error is better than 1.2°. The resolution of the measurement system is better than 0.1° at all temperatures. Provided the field strength of 100 kA/m (1250 Gauss) is used for the magnetic system, the hysteresis lies within the resolution and is therefore not measurable.

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1 INTRODUCTION

Magnetoresistive sensors (MR sensors) of Philips Semiconductors make use of the fact that the electrical resistance of certain ferromagnetic alloys, such as permalloy, is influenced by external magnetic fields. This solid state magnetoresistive effect - or anisotropic magnetoresistance (AMR) - is easily realised in thin film technology, allowing the production of precise but also cost-effective sensors.

As the magnetoresistive effect is naturally an angular effect, its utilization for contactless angle measurement systems fits perfectly. The underlying principle is simple: the electrical resistance of the permalloy strip changes with the angle between the internal magnetization vector in the strip and the vector of electrical current flowing through it. Consequently, to achieve accurate measurements, the only condition to be met is that the internal magnetization vector of the permalloy must directly follow an external magnetic field vector. This is ensured when using an external field strength much higher than the internal magnetization. As this strong external field saturates the sensor, the actual field strength has no impact on the measurements. Only the direction of the field is evaluated. This leads to the following advantages of magnetoresitive angle measurement systems:

- Independence of magnetic drift during life time.
- Independence of magnetic drift with temperature.
- Independence of mechanical assembly tolerances.
- Independence of mechanical shifts caused by thermal stress.

Moreover, the small offset drift of the sensor signals requires no compensation for temperature effects, which simplifies implementation.

Additionally, MR based systems show the same advantages as all other contactless measurement systems; they are free of wear and they can be completely encapsulated making the sensor modules robust regarding contamination and mechanical destruction. All these advantages recommend magnetoresistive angle measurement systems for applications requiring very robust and precise but also cost-effective solutions. This, for example, is the case in all automotive applications.

To support users who want to build up a contactless angle measurement system, Philips Semiconductors provides a two-chip solution consisting of the magnetoresistive sensor KMZ41 and the sensor signal conditioning IC UZZ9000 (analog output) and UZZ9001 (digital output). The ICs were designed for the usage with the KMZ41 and therefore provide an optimised interface to this sensor.

The intention of this paper is to provide the necessary background information for system design. After giving a short introduction in the MR technology for angle measurement and discussing basics of possible system set-ups, both the KMZ41 and the UZZ9001 are described in more detail. Besides electrical characteristics and functional behaviour, main items are the correct choice of the magnet arrangement and the trimming procedure to compensate the static offsets of the sensor. The last

section describes non-ideal cases and their impact on system accuracy. A proposal is made how to calculate the achievable system accuracy under different system constraints.

2 MAGNETORESISTVE SENSOR TECHNOLOGY FOR ANGLE MEASUREMENT

Magnetoresistive (MR) sensors make use of the magnetoresistive effect, the property of a current carrying magnetic material to change its resistance in the presence of an external magnetic field. Figure 1 shows a strip of ferromagnetic material, called permalloy.

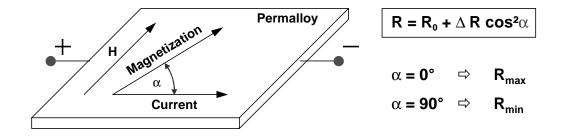


Figure 1: The magnetoresistive effect in permalloy

Assume that, when no external magnetic field is present, the permalloy has an internal magnetization vector M parallel to the current flow ($\alpha = 0$). If an external magnetic field H is applied, parallel to the plane of the permalloy but perpendicular to the current flow, the internal magnetization vector of the permalloy will rotate around an angle α . As a result, the resistance R of the permalloy will change as a function of the rotation angle α , as given by:

$$R = R_0 + \Delta R_0 \cos^2 \alpha \tag{1}$$

 R_0 and ΔR_0 are material constants. To achieve an optimum sensor characteristics, Philips use Ni19Fe81, which has a high R_0 value and low magnetostriction. With this material, ΔR_0 is in the order of 2 to 3%. It is obvious from this quadratic equation that the resistance to magnetic field relation is non-linear. It becomes also clear that the magnetoresistive effect is naturally an angular effect recommending its utilisation for angle measurement applications. Here the external magnetic field carries the measurement information between sensor and physical value to be measured.

Having this principle of operation in mind, it becomes clear that the precondition to achieve accurate measurements is that the internal magnetization vector M must directly follow the vector H of the external field. This can be achieved by applying an external field H much higher than the internal field of approximately 3 kA/m. When using the KMZ41 for angle measurement, it is recommended to provide an external field of at least

$$H \ge 100 \text{ kA/m}$$
 (1250 Gauss). (2)

In that case the two vectors M and H are virtually parallel to each other.

Normally, the external magnetic field is generated by permanent magnets, e.g. SmCo types. Figure 2 shows a basic set-up, where the angular position of a rotating shaft is measured with the help of the permanent magnet fixed to it.

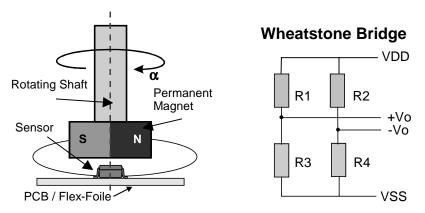


Figure 2 Basic arrangement of sensor and magnet for contactless angle measurement.

The magnetoresistive angle sensors of Philips Semiconductors are etched on a silicon substrate, with four permalloy strips arranged in a Wheatstone bridge configuration. According to the basic relationship given by Equation (1), the differential output signal (+Vo, -Vo) of such a Wheatstone bridge is proportional to $\sin 2\alpha$. This means that a sensor comprising one Wheatstone bridge can measure an angular range of 90°. This is visualised in Figure 3.

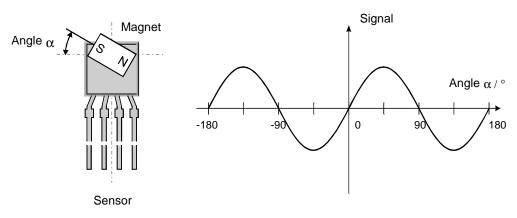


Figure 3: Output signal from a single Wheatstone bridge sensor

Apart from the limited angular range, the single bridge sensor shows another disadvantage regarding signal evaluation. As the signal amplitude changes with temperature, the output signal of the sensor forces the user to implement temperature compensation. This is avoided when using a two-bridge arrangement combined with a signal evaluation explained below. Figure 4 shows the principle.

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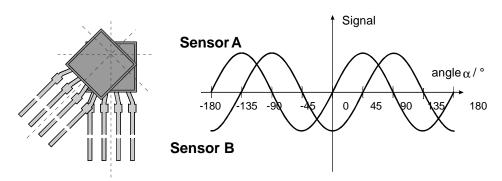


Figure 4 Output signal from a double Wheatstone bridge sensor (KMZ41)

The two sensor bridges are positioned at an offset angle of 45° to each other. In this arrangement, the two output signals show an electrical phase shift of 90°. The two signals are therefore proportional to $\sin 2\alpha$ and $\cos 2\alpha$, respectively.

Even in this arrangement, the signal amplitudes will change with temperature. However, both bridges are processed in the same thin film process steps on the same substrate and they will therefore show very similar characteristic. Assuming that both output signals have no offsets or offsets have been compensated previously, the output signals can be described mathematically as follows:

$$X(\alpha,T) = X_0(T)\sin 2\alpha$$

$$Y(\alpha,T) = Y_o(T)\cos 2\alpha$$
(3)
(4)

Assuming further that the amplitudes of both signals are really identical ($X_0 = Y_0$), the unknown angle α can be determined without any error from the signals *X* and *Y* as given by Equation (5):

$$\alpha = \frac{1}{2} \arctan\left(\frac{X}{Y}\right) \tag{5}$$

This result does not depend on the absolute amplitude of the signals. Consequently, temperature measurement and compensation of the temperature effects is not required.

Of course, due to the non-ideal manufacturing process, a real sensor will not show the ideal behaviour assumed above. A detailed discussion of these non-ideal cases and their impact on system accuracy can be found in section 7.

3 SYSTEM OVERVIEW

An angle measurement system requires one sensor KMZ41 and one sensor signal evaluation IC UZZ9001. Figure 5 shows the block diagrams of both components:

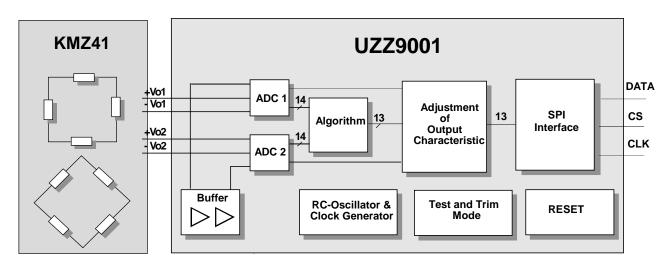


Figure 5: Block diagram of the two-chip measurement system

The differential sensor signals +/-Vo1 and +/-Vo2 of the KMZ41 are sampled by the UZZ9001 input stage and then are converted into the digital domain. This conversion is done with the help of two separate but simultaneously clocked Sigma-Delta AD converter [4]. The digital representations of the two signals are then used to calculate the angle. For this calculation the CORDIC algorithm is used. CORDIC is nothing else than an iterative way to calculate the inverse tangent function of both signals without extensive numerical overhead. Details of the CORDIC algorithm can be found in reference [3]. Afterwards, the current angle represented as a 13-bit digital value can be read from the SPI.

As mentioned before, the sinusoidal input signals coming from the KMZ41 may have a static offset that must be compensated to get accurate results. This compensation is done separately for each channel by providing an analog voltage to special pins of the UZZ9001. These voltages (OFF1, OFF2) must be provided continuously during operation as compensation is done real time and not stored at system start. As KMZ41 and UZZ9001 are not sold as one unit, the user is responsible for providing the correct compensation voltages. The UZZ9001 provides some special functions for the trimming process, which are described in section 5.

Apart from the features described above, the UZZ9001 provides an on-chip RC-Oscillator generating the clock for the IC's state machine. Consequently, no external clock reference is required for system operation. Moreover, the UZZ9001 has a power-down and power-up reset with build-in hysteresis. This reset block automatically generates a reset signal during power-on or if the save voltage range is left.

4 SENSOR KMZ41

The magnetoresitive sensor KMZ41 of Philips Semiconductors has been designed for angle measurement applications, preferably in combination with the signal conditioning IC UZZ9001. The application relevant items are discussed in the following sections. The KMZ41 properties affecting the system accuracy are discussed in section 7. Please refer to the latest data sheet to get actual specification data of the KMZ41.

4.1 Layout of the KMZ41 Sensor

The KMZ41 comprises two complete Wheatstone bridges made on the same substrate in thin film technology. Therefore both bridges show a very good matching regarding electrical and mechanical properties. Figure 6 shows the layout of the sensor.

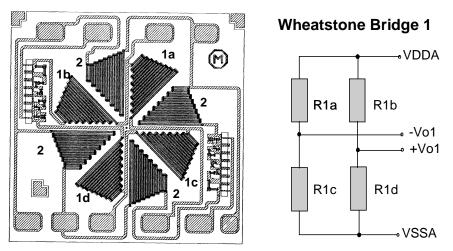


Figure 6: Layout of the double bridge sensor KMZ41. 1a to 1d indicate the sensitive elements of Wheatstone bridge 1

Moreover, the different sensitive elements of Wheatstone bridge 1 are marked. Both bridges have separate connections for supply voltage. The die size of the KMZ41 is about 1.5 mm² with a sensitive area of about 1 mm².

In order not to influence the external magnetic field and therefore the accuracy of measurements, the lead frame of the KMZ41 is made without use of ferrous material. Please note that with respect to a good system design it is also important not to place elements consisting of ferrous material very close to the KMZ41.

4.2 Input and Output Signals

The KMZ41 is housed in a SO8 package. The pinning is given in TABLE 1.

TABLE 1: Pinning of the KMZ41

Pin	Symbol	Type*	Description
1	-Vo1	А	negative output voltage of bridge 1
2	-Vo2	А	negative output voltage of bridge 2
3	Vcc2	А	supply voltage bridge 2
4	Vcc1	А	supply voltage bridge 1
5	+Vo1	А	positive output voltage of bridge 1
6	+Vo2	А	positive output voltage of bridge 2
7	GND2	А	Ground bridge 2
8	GND1	А	Ground bridge 1

* A = analog pin, D = digital pin

Apart from the two separate supplies, the KMZ41 provides two differential signal lines for each Wheatstone bridge. The following discussion assumes that the external magnetic field is strong enough to saturate the sensor. This ensures that each bridge of the KMZ41 has a sinusoidal output voltage as given in Figure 7.

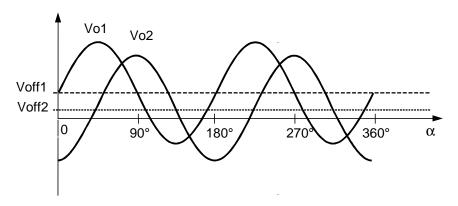


Figure 7: Output signals of the KMZ41

Ideally, these signals would have no static DC offset. However, static offsets cannot be completely avoided due to manufacturing tolerances. As these DC-offsets Voff1 and Voff2 affect the system accuracy, they must be compensated by the signal conditioning IC. The UZZ9001 provides special build-in functions for this task. Please note that Figure 7 is drawn exaggerated to emphasize the effect, the actual sensor has much smaller offsets.

The amplitudes of the output signals depend on both the supply voltage and the ambient temperature. Because of the ideal thermal coupling, the temperature coefficients of both bridges are almost identical. The MR effect exhibits a negative temperature coefficient. This means that with higher temperatures, the signal amplitude decreases and vice versa. A short example demonstrates this effect:

The typical temperature coefficient (TCVpeak) for the KMZ41 is -0.31 % / K. Consequently, based on a known peak voltage at room temperature, the peak voltage at any other temperature T can be calculated as follows:

$$Vpeak_{T} = Vpeak_{25^{\circ}C} * \left(1 + (T - 25^{\circ}C) * \frac{TCVpeak}{100\%} \right)$$
(6)

To give an example, the peak voltage of the KMZ41 at room temperature and 5V supply is typically Vpeak_{25°C} = 78 mV. Consequently, at T = 125 °C, a peak voltage of Vpeak_{125°C} = 53.8 mV can be expected. At -40°C, however, the peak voltage increases to Vpeak_{40°C} = 93.7 mV. This effect does not affect the system accuracy when using the signal processing implemented in the UZZ9001.

Besides the signal amplitude, also the DC offset drifts with temperature. However, this offset drift is so small that it needs no compensation in normal applications. The offset drift and its impact on system accuracy are discussed in section 7.

4.3 Magnets and Magnet Arrangements

It is recommended to use the KMZ41 in a magnetic field saturating the sensor. This is guaranteed when the field strength is above 100 kA/m in the sensitive area of the sensor.

The most simple magnet arrangement is that of a block magnet rotating directly above the KMZ41 as depicted in Figure 2. The effective magnetic field strength of such a block magnet arrangement depends on the distance between magnet and sensor, magnet size and magnet material. Because of strong field requirements, the usage of rare earth magnets such as SmCo or NeFeB is recommended.

Figure 8 shows the field strength of three sample magnets as a function of the distance between magnet and the top of the sensor package. It becomes clear that only the SmCo type achieves field strengths of 100 KA/m and more for distances below 0.8 mm. Its dimension of 8x3x7.5 has been chosen due to economic aspects and is used in several applications. Stronger fields allowing larger distances, this can be achieved easily when using thicker but more expensive magnets, e.g. a SmCo 8x4x7.5. Please note that the underlined dimension characterises the direction of magnetization.

In low-end applications, however, a low system price may be more important than excellent system accuracy. As a consequence, here it may be adequate to use cheaper magnets not saturating the sensor, e.g. FXD types. The additional error induced by this measure is discussed in section 7.

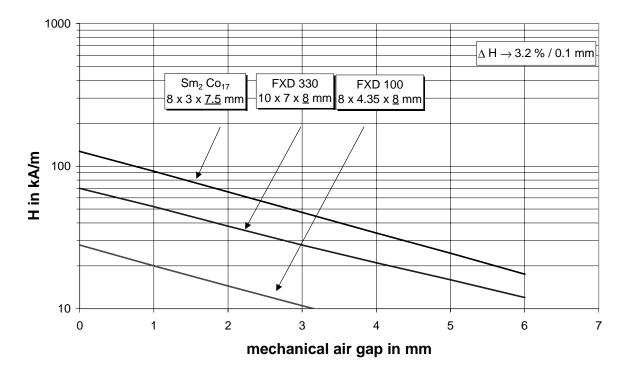
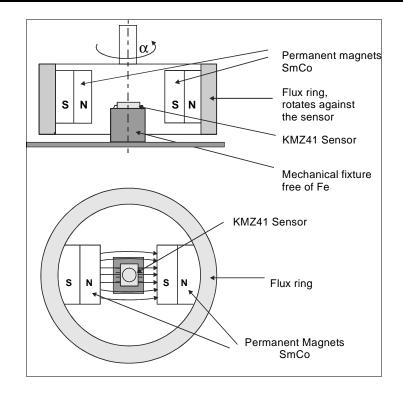
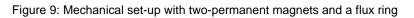


Figure 8: Field strength in the sensitive plane of the KMZ41 in dependence of the air gap between the top of the sensor package and the block magnet. The underlined dimension characterises the direction of magnetization.

4.4 Other Mechanical Set-ups

The usage of a block magnet rotating above the sensor is only one simple possibility for a magnetic system set-up (Figure 2). Meanwhile, several application specific solutions were built. These set-ups use flux rings and flux guides. Figure 9 shows the general arrangement of such a magnetic system. The inner walls of the flux ring carry the permanent magnets. This unit rotates around the fixed sensor (for example KMZ41). The two permanent magnets generate a more homogenous field inside the ring than the basic arrangement as shown in Figure 2. The additional use of the flux ring makes a shielding against external fields possible.





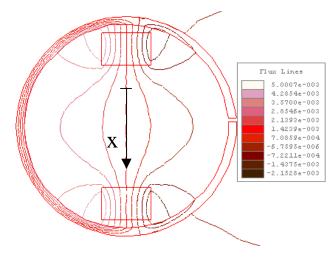
Simulation results of different magnetic arrangements are shown in

- Figure 10 (two-magnet arrangement),
- Figure 11 (four-magnet arrangement) and
- Figure 12 (ring-magnet arrangement).

Each Figure shows the simulated flux lines in dependence of the magnet arrangement. In each arrangement the same magnetic flux ring and magnetic material is applied (SmCo). The magnetic arrangements produce different magnetic fields with respect to strength and homogeneity.

It is obvious that the ring-magnet arrangement has the most homogeneous magnetic field in comparison to the other magnet arrangements. The arrangement with two-magnets seems to be more inhomogeneous as the four-magnet arrangement.

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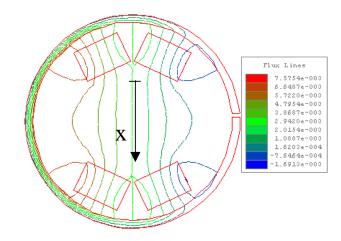


Figure 10: Flux lines of a two-magnet arrangement

Figure 11: Flux lines of a four-magnet arrangement.

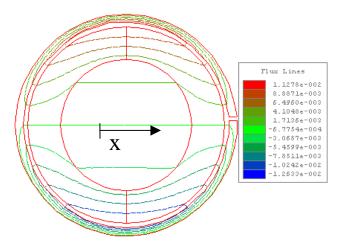


Figure 12: Flux lines of a ring-magnet arrangement

Figure 13 shows the simulated magnetic field strength H of these magnetic arrangements. The relevant position (X-Position) for the sensor is also shown in Figure 10 to Figure 12.

The ring-magnet arrangement generates the most homogeneous magnetic field in comparison to the other magnetic arrangements. The arrangement of four-magnets achieves a little bit more inhomogeneous result as the ring magnet. The simulated magnetic field strength reaches a value up to $H_{simulation} = 180$ kA/m and is quite similar between both magnetic arrangements. Overall the four-magnet arrangement can be an alternative to the ring-magnet arrangement.

The two-magnet arrangement achieves a significant lower magnetic field strength. At the relevant sensor position a magnetic field strength of $H_{simulation} = 105$ kA/m is achieved. The parabolic curve is disadvantageous in comparison to the homogeneous magnetic field of the ring-magnet. Therefore

this solution can be a compromise between the system accuracy and the system costs. The mechanical set-up for this simulation is shown in Figure 9.

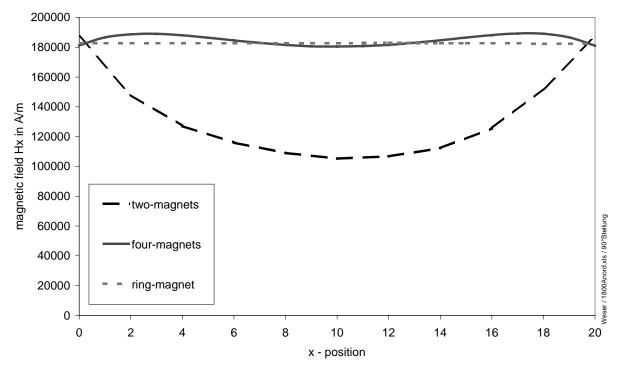


Figure 13: Simulation of the magnetic field strength H_{simulated} for different magnet arrangements (two-, four-magnet and ringmagnet arrangement)

Therefore the magnet arrangement (diameters, dimensions of the flux ring and the magnets) must be dimensioned application-specific. The mean targets of optimisation are:

- Concentration of the magnetic field in order to allow the usage of weaker magnets (ferrite instead of rare earth).
- Making the magnetic field homogenous in a wider range to tolerate larger mounting tolerances.
- Shielding of the primary field against external fields.

A final solution will be a compromise between system accuracy and system costs.

5 SIGNAL CONDITIONING IC UZZ9001

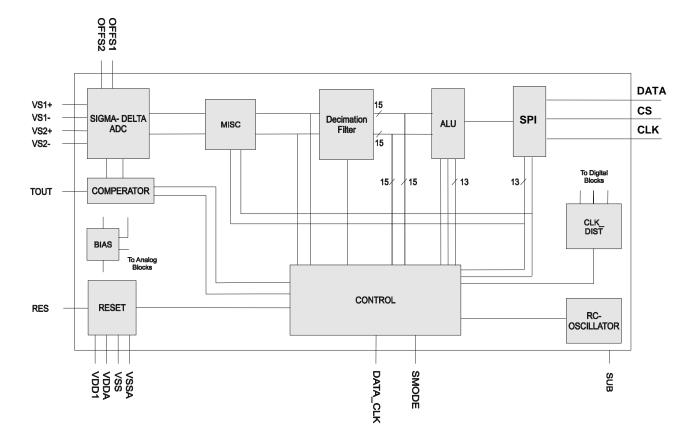
The UZZ9001 is a signal IC for angle calculation. It combines two sinusoidal signals (sine and cosine) into one digital output signal. The UZZ9001 can be used in conjunction with any sensor that encodes a mechanical angle into two sinusoidal signals with 90° phase shift. The UZZ9001 is very similar to the UZZ9000, which is described in the Application note AN98097. Instead of the analog signal output, the UZZ9001 provides a digital output. The digital output stage implements the Motorola Serial Peripheral Interface (SPI). Moreover, the UZZ9001 operates in 180° mode only and provides no possibility to adjust the mechanical offset like the UZZ9000. The UZZ9001 has an overall accuracy better than 0.35° assuming ideal inputs. This limit holds over the specified ambient temperature range of -40°C to +150°C. The Pinning of the UZZ9001, the input and output characteristic and the trimming process are discussed in the following sections.

5.1 General Description

The basic operation of the UZZ9001 has already been described in section 3. Within this section, some more details should be addressed that might be useful for a system designer. The detailed block diagram of the UZZ9001 is given in Firgue 14.

The following list gives a short description of the relevant blocks.

- 1. The **ADC** block contains two Sigma Delta AD converters for the sensor signals and a sensor offset correction circuitry.
- 2. **DF** stands for the two digital low pass decimation filter which convert the low resolution high speed bit stream coming from the Sigma Delta converters into a low speed digital word.
- 3. The **ALU** block derives an angle value from the two digital inputs using the CORDIC algorithm.
- 4. The **SPI** converts the digital angle value from parallel into serial data, which can be clocked out by the user.
- 5. The block **CNTRL** provides the clock and the control signals for the chip.
- 6. The **COMP** block generates binary output signals used for sensor trimming.
- 7. The **RESET** block supplies a reset signal during power-up and power-down when the power supply is below a certain value.
- 8. The **OSC** unit generates the master clock



Firgue 14: Detailed block diagram of the UZZ9001

On entering the IC, the analog measurement signals are converted to digital data by an ADC. The ADC is a Sigma-Delta modulator, employing a 4th order continuous time architecture, with an oversampling ratio of 128 to achieve high resolution. The output of the converter is a digital bit-stream at the over-sampling frequency of typically 500 kHz. The bit stream is fed into a decimation filter, which performs both low-pass filtering and down sampling. There are two input channels of the IC, each of which has its own ADC and decimation filter. The two decimation filter outputs are digital words of 15bit at a lower frequency of typically 3.9 kHz. This is the typical sampling frequency of the sensor system. The digital representations of the two signals are then used to calculate the current angle. This calculation is done using the so-called CORDIC algorithm. The angle is represented with a 13-bit resolution accessible via the SPI (Serial Peripheral Interface).

The SPI is a byte-orientated synchronous serial master-slave bus system. The UZZ9001 has a SPI that operates in slave mode only. A configuration of the UZZ9001 via the SPI is not possible and therefore an input data line is not required.

The general arrangement of such a basic slave SPI interface is shown in Figure 15. All signals are related to the common VSS line (digital ground). Only a master SPI module (Electronic Control Unit, ECU) can initiate transmissions. Therefore, the start of the transmission is indicated by setting the CS pin to logical low (signal is active low), by the master module. Then the master module can "clock out"

the required data from the shift register. This transfer mode and details of the timing are specified in section "Serial Peripheral Interface (SPI)".

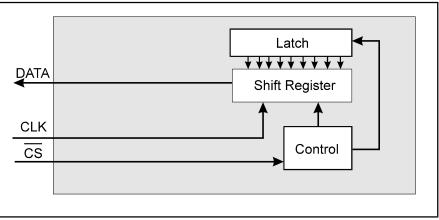


Figure 15: Slave-SPI Block Diagram

5.2 Pinning of the UZZ9001

The following **Table 2** gives the pinning of the UZZ9001 that comes in a standard SO24 package.

Pin	Symbol	I/O*	Type*	Description
1	+Vo2	Ι	А	positive output voltage of sensor 2 (Wheatstone bridge 2)
2	+Vo1	I	А	positive output voltage of sensor 1 (Wheatstone bridge 1)
3	VDD	S	А	digital supply
4	VSS	S	А	digital ground
5	VSSA	S	А	analog ground
6	RES	I	D	resets the digital part of the UZZ9001, pin is active high. If not used, pin can be left unconnected (internal pull-down resistor) or connect it to ground.
7	TEST1	I	D	used for production tests, can be left unconnected (internal pull-down resistor) or connect it to ground
8	TEST2	0	D	used for production tests, must be left unconnected
9	DATA_CLK	I	D	data clock, used when setting the UZZ9001 into trim mode, can be left unconnected (internal pull-down resistor) or connect it to ground
10	SMODE	I	D	serial mode programmer, used when setting UZZ9001 into

Table 2 Pinning of the UZZ9001

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Pin	Symbol	I/O*	Type*	Description
				trim mode, can be left unconnected (internal pull-down resistor) or connect it to ground
11	TEST3	0	D	used for production tests, must be left unconnected
12	DATA	0	D	DATA pin of the SPI.
13	CLK	I	D	Data clock of the SPI.
14	CS	Ι	D	Chip Select of the SPI.
15	OFF2	Ι	А	offset trimming input for sensor 2 (Wheatstone bridge 2)
16	OFF1	Ι	А	offset trimming input for sensor 1 (Wheatstone bridge 1)
17	VDDA	S	А	analog supply
18	VSSA	S	А	analog ground
19	TEST4	I	D	used for production tests, can be left unconnected (internal pull-down resistor) or connect it to ground
20	TEST5	I	D	used for production tests, can be left unconnected because of an internal pull-down resistor or connect it to ground
21	VDD	S	А	digital supply
22	TOUT	0	D	used in trim mode, gives the offset corrected signal of sensor 1 or sensor 2, must be left unconnected in application
23	-Vo2	Ι	А	negative output voltage of sensor 2 (Wheatstone bridge 2)
24	-Vo1	Ι	A	negative output voltage of sensor 1 (Wheatstone bridge 1)

* A = analog pin, D = digital pin, S = supply, I = input, O = output

5.3 Characteristics of the Input Signals

The input stage of the UZZ9001 expects two sinusoidal signals (section 4.2). The electrical characteristics of these signals are defined in TABLE 3. These values correspond to the KMZ41 sensor specification.

Parameter	Min	Мах	Units	
Analog supply voltage	4.5	5.5	V	
Differential input voltage range (peak voltage)	+/- 6.6*	+/- 28	mV / V	

TABLE 3: Limits of the UZZ9001 input signals

Parameter	Min	Мах	Units
referred to analog supply voltage			
(including any offset)			
Differential input voltage offset referred to analog supply voltage	-2	+2	mV / V
Common mode range referred to the analog supply voltage	490	510	mV / V

* If signals of both channels are below this limit at the same time, the magnet lost error condition becomes active (see section 5.6).

5.4 Characteristic of the Output Signal (SPI-Pins)

The digital output signal of the UZZ9001 is coded in 14 bits named D13 to D0. Within these 14 bits, the coding of the angle uses 13 bits (D12 to D0). One bit (D13) is reserved to indicate error and diagnostic conditions.

The 14 data bits (D13-D0) are arranged in 2 Bytes as shown in Figure 16. D13 is the MSB of the sensor signal and D0 is the LSB of the sensor signal. Byte 2, which is sent first, contains the data bits D13 to D7 and additionally the parity bit P2 which is added to allow the recognition of disturbed messages. P2 gives the ODD Parity of the data bits D13 to D7 and has to be evaluated by the master module.

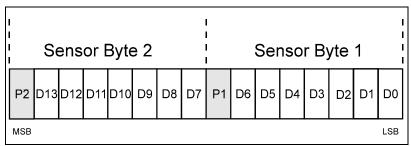


Figure 16: Coding of the digital output

Similar, Byte 1 comprises data bits D6 to D0 and the parity bit P1, which gives the ODD Parity of the data, bits D6 to D0. The ODD parity is chosen to detect failure modes where the DATA pin is short-circuit to GND or VDD or where the connection between DATA out of the slave and DATA in of the master is interrupted (e.g. broken wire).

The error and diagnostic conditions are indicated by D13 = 1 (logical high). In this case, the last two bits (D0 and D1) specify the error case. All other bits (D3 - D12) still shows the current measurement value. Consequently, the two least significant bits are lost for the measurement representation, which results in 11-bit resolution in error and diagnosis cases. Whether the measurement value is reliable or

not depends on the special error case and has to be evaluated by the master unit. The coding is specified in Table 4.

D1	D0	Case	Measurement value reliable	Comments / Remarks
0	0	No valid value presently available due to RESET	No	
0	1	Magnet Lost	No	
1	0	reserved	-	
1	1	reserved	-	

The output stage of the UZZ9001 (DATA pin) is able to drive any external output load as defined in TABLE 5. This output changes from direct connection to VSS to output active (driver active) in dependence of the CS line.

TABLE 5: Static Operating Characteristics of the DATA Pin

Symbol	Parameter	Min	Nom	Max	Units
V _{ol}	Output voltage "LO"			0.4	V
V _{он}	Output voltage "HI"	V _{DD} - 0.8		V _{DD}	V
I _o	Output current			10	mA
	(Peak Driver Capability)				
C _{OUT}	Output capacitance (Note1)		150		pF

Note 1: C_{out} should chosen adequately in combination with a resistance in order to limit I_o during switching to the specified maximum value

The requirements of the other digital signals (CLK and CS pins) of the SPI are given in **Table 6**. This signals are input signals of the SPI and necessary for the digital output signal on the DATA Pin.

Symbol	Parameter	Min	Тур	Max	Unit
V _{IL}	Input voltage "LO"	0		0.3 * V _{DD}	V

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V _{IH}	Input voltage "HI"	0.7 * V _{DD}		V _{DD}	V
I,	Input current		10		uA
C	Input capacitance		10		pF

5.5 Serial Peripheral Interface (SPI)

This chapter gives a general overview on the pin characteristics, their interrelationships and timing requirements.

5.5.1 CS Pin

The Electronic Control Unit (ECU) selects the UZZ9001 via the CS pin, which is active low. Whenever the pin is in a logic low state, the DATA pin output driver is enabled allowing data to be transferred from the UZZ9001 to the ECU. Consequently, on the falling edge of the CS signal, the DATA output driver changes from fixed connection to Vss into active mode which means it drives the actual data bit level onto the DATA line. CS is active (low) during data transmission. With the leading edge of CS, DATA changes again from active state to fixed connection to Vss. Additionally the edges on the CS line are used to up-date the SPI Shift Register content.

5.5.2 CLK Pin

The system clock (CLK) clocks the internal shift registers of the UZZ9001. With every falling edge of CLK, the register is shifted by one position and therefore the next data bit level is driven on the DATA line. The bit level is sampled (by the master) at the next leading edge of the CLK signal. Due to synchronisation requirements of the internal logic of the UZZ9001 and to ensure correct SPI timing conditions, the CLK pin must be held on a constant "logical high" level whenever a transition of the CS signal occurs. The master unit provides the timing of the CS and CLK Signal, therefore the designer of the ECU is responsible for meeting these timing requirements. Details of the SPI Timing are specified in section "SPI-Timing" (5.5.4).

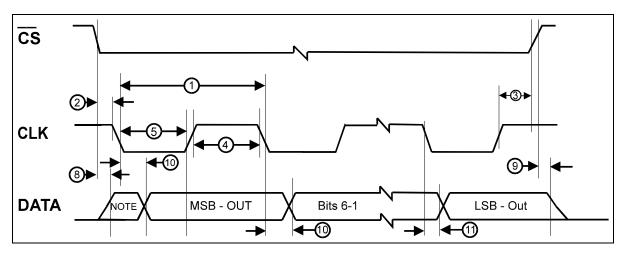
5.5.3 DATA Pin

The serial output (DATA) pin is the output from the shift register. It operates as push-pull driver. If CS is not active, the pin is connected to Vss. An external serial resistor will limit the current if inadvertently the line is connected to VDD. The DATA pin remains in this state until the CS pin goes to a logic low state. When CS is active then the DATA pin push-pull output driver is activated and drives the present data bit level onto the bus line.

5.5.4 SPI-Timing

As a slave node the UZZ9001 provides only one operation mode. With respect to Motorola SPI devices, this mode is selected by setting CPHA = 1 and CPOL = 1.

In this transfer mode the data bits are sampled by the master unit using the leading edge of the clock, as shown in Figure 17. The falling edge indicates that the next data bit has to be provided by the slave device (shift operation).



NOTE: Not defined data, normally LSB of character previously transmitted Figure 17: UZZ9001 SPI Interface Timing

The timing requirements of the SPI interface are given in the following table:

TABLE 7: SPI-Timing:

Diagram Number	Parameter	Symbol	Min	Мах	Unit	Remarks / Test Conditions
	Operating Frequency	f _{op}	DC	1	MHz	
1	Cycle Time	t _{cyc}	1	-	us	
2	Enable Lead Time	t _{Lead}	15		ns	Determined by master module
3	Enable Lag Time	t _{Lag}	15		ns	Determined by master module
4	Clock High Time	t_{clk_high}	100	-	ns	Determined by master module
5	Clock Low Time	t _{clk_low}	100	-	ns	Determined by master module
8	Access Time	t _{acc}	0	20	ns	Time to data active

Diagram Number	Parameter	Symbol	Min	Max	Unit	Remarks / Test Conditions
						from fixed V_{ss} state
9	Disable Time	t _{dis}	-	25	ns	Hold time to fixed V_{ss} state
10	Data Valid Time	t _v	-	40	ns	With 100 pF on all
	(After Clock Edge)					SPI pins
11	Data Hold Time	t _h	5	-	ns	
	(Output, After Clock Edge)					
	Transmission Delay	t _{Delay}	1.2		us	
	(Time between the leading edge of CS until the next falling edge)					

Another advantage of the chosen operation mode is that the CS pin has not to be toggled between the transmission of more than one byte. This lightens the two byte operation of the UZZ9001 as explained below. The timing of the CS line during transmission of the two sensor bytes is shown in Figure 18.

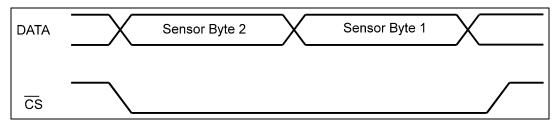


Figure 18: Timing of the CS Line

The transmission may be stopped by the user at any time. A leading edge at the CS pin will initialise the SPI Shift Register allowing the start of a complete new transmission. If the CS line is held low (active) during stop of transmission, the stopped transmission can be continued without loss of data.

5.6 Offset Trimming

For a correct output signal, it is necessary to adapt the offsets of the two input signals to the input stage of the UZZ9001. For this reason a sensor offset cancellation procedure was implemented in the

UZZ9001 which is started by sending a special serial data protocol to the UZZ9001. This trimming procedure is required for both input signals.

5.6.1 Trim Interface

The serial interface used to switch the UZZ9001 into trim mode consists of the two terminals SMODE (pin 10) and DATA_CLK (pin 9). The structure of this protocol is shown in Figure 19.

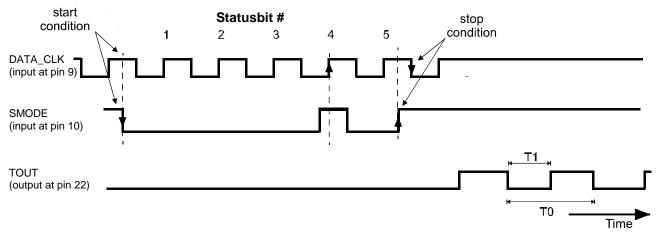


Figure 19: Protocol used to set the UZZ9001 into trim mode.

All signal levels at DATA_CLK and SMODE must be chosen according to the requirements listed in TABLE 8. Because of the asynchronous protocol, the following points have to be taken into account:

The protocol starts with a falling edge at SMODE, which must occur at a high level of the DATA_CLK. The next five bits are used for coding of the message send to the UZZ9001. They are transferred via SMODE and are sampled with the rising edge of DATA_CLK. During the fifth high level output of DATA_CLK (counted from the start condition onwards), a rising edge must appear at SMODE and afterwards DATA_CLK has to change one more time to low level in order to successfully complete the protocol.

Parameter	Min	Nom	Max	Unit
supply voltage VDD of UZZ9001	4.5	5.0	5.5	V
low level of DATA_CLK, SMODE	0		5	%VDD
high level of DATA_CLK, SMODE	95		100	%VDD
rise and fall time of signal edges of DATA_CLK and SMODE	8			ns
(from 10% VDD to 90% VDD and				

Parameter	Min	Nom	Max	Unit
vice versa)				
Frequency of DATA_CLK	0.1		1	MHz

5.6.2 How to Enter the Trim Mode

The status bits to be transmitted to the UZZ9001 are shown in TABLE 9. Also please note that a complete protocol has to be sent to return to normal operation. Another possibility to leave the trim mode is to reset the device.

TABLE 9: Programming of trim modes

Mode	Status Bits				
	1	2	3	4	5
enter trim mode for sensor input channel 1	0	0	0	1	0
enter trim mode for sensor input channel 2	0	0	1	0	0
leave trim mode for either input channels	0	0	0	0	0

After entering one of the trim modes, a square wave output is visible at the terminal TOUT (pin 22) provided there is a dynamic input signal.

5.6.3 Offset Calibration

To make use of the build-in trimming procedure of the UZZ9001, it is necessary to generate dynamic sensor signals at its inputs. When the KMZ41 is used, a rotating permanent magnet in front of the sensor can easily generate these input signals. The principle of this set-up is shown in Figure 20.

Please note that the absolute rotational speed of the permanent magnet is not that important but it must be constant over time. Please further note that the rotational axis of the motor and magnet must be aligned exactly with the center of the KMZ41 package as shown in Figure 20. It is not necessary to use the same magnet for both trimming and application, but after trimming, the KMZ41 and UZZ9001 must be treated as one unit. The trimming procedure is as follows.

When the UZZ9001 has been switched to trim mode and sinusoidal sensor voltages are applied to its inputs, then the terminal TOUT (pin 22) immediately shows a square wave signal. This square wave

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signal has the same frequency as the sensor signal and a duty cycle T1/T0 as shown in Figure 19 previously.

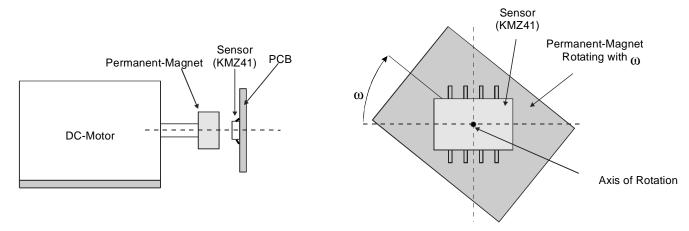


Figure 20: Proposal for a mechanical set-up to trim the UZZ9001

At a duty cycle of 50%, the offset for the selected channel is virtually eliminated. Therefore, the voltage at OFF1 (PIN16, channel 1) or OFF2 (PIN15, channel 2), respectively, has to be adjusted until this target is achieved. The trimming voltages OFF1 and OFF2 must be ratiometric to the UZZ9001 VDDA supply and must not vary more than 0.1 % VDDA with temperature and over lifetime. As already proposed for adjusting the angular ranges and zero point offset, these properties can be ensured, for example, when using a trimmable resistor divider connected to VDDA.

When building up an automatic trimming station for mass production, it is recommended to firstly determine the actual trim voltage to be fed to OFF1 and OFF2 as a fraction of VDDA. Afterwards, the resistor dividers are trimmed according to the requirements found. This procedure will be much faster compared with trying to trim the resistors step by step to get 50% duty cycle. In practice, laser trimmable resistors used for both divider elements have shown good results. Using resistors of the same material is important to get a similar temperature coefficient. Please note that for duty cycle measurements, the measuring device should be set into averaging mode in order to eliminate the influence of short spikes or noise. TABLE 10 summarises the recommended trim parameters:

Parameter	Symbol	Min	Nom	Max	Unit
Frequency of the motor	fo	20		30	S ⁻¹
Frequency of the sensor input signals (KMZ41)	2 fo	40		60	Hz
Stability of the rotational speed over one signal period	Δf			0.05	% fo

Parameter	Symbol	Min	Nom	Max	Unit
Limits for the duty cycle of nominal 50% during trimming		49.96		50.04	%
Variation of the voltages provided at OFF1 and OFF2 with temperature and during lifetime				0.1	%VDDA
Voltage range for OFF1 and OFF2		33.3		66.7	%VDDA
Input signal offset range to be aligned by OFF1 and OFF2. Values are referred to VDDA. The min value corresponds to the min value for OFF1 and OFF2 (33.3% VDDA), and vice versa.		-2		2	mV / V

Example:

The following example serves to demonstrate the meaning of these limits and allows the calculation of the system accuracy if other values are applied.

Assuming sinusoidal sensor signals with the amplitude *A*, then the relation between an DC offset Δx and the measured duty cycle T1/T0 is as follows:

$$\Delta x = A \sin\left(\pi \cdot \left(0.5 + T1/T0\right)\right) \tag{7}$$

At room temperature and 5V supply voltage, the typical signal amplitude *A* of the KMZ41 is 78 mV. Consequently, at a duty cycle of 50.04% (or 49.96%) the remaining offset voltage is:

$$\Delta x = 78 \ mV \sin(\pi \cdot (0.5 + 0.5004)) = -0.098 \ mV \tag{8}$$

As a result, the remaining offset is 0.13% referred to the signal amplitude of 78 mV. The angular error caused by this offset is discussed in section 7.

The other parameter specified is the drift of the voltages applied to OFF1 and OFF2 with temperature and over lifetime. It is specified to be less than 0.1% VDDA. The maximum voltage range for OFF1 and OFF2 is 33.3 % VDDA which is used to align the input signal offset range of +/- 2 mV / V. Consequently, changes of OFF1 or OFF2 by 0.1% VDDA will cause offset voltages Δx of:

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$$\Delta x = \frac{0.1\% \text{ VDDA}}{33.3\% \text{ VDDA}} \cdot 2 \cdot 2 \text{ mV} / \text{V} = 0.012 \text{ mV} / \text{V}$$

At a supply voltage of 5V, the offset voltage caused by the drift of OFF1 and OFF2 is 0.06 mV for each channel. The resulting angular error due to this offset is discussed in section 7.

5.7 Reset

In addition to the external reset pin (pin 6), the UZZ9001 provides an internal power-up / power-down reset logic which supervises the supply voltage continuously. When the supply voltage increases and reaches a safe level, reset becomes inactive and the device starts initialization after a nominal delay of 100 us. This is to ensure settling of all analog and digital sections. When the supply voltage leaves the safe voltage level, the device is reset immediately. This internal reset logic can be over-ridden by the external pin RES (pin 6) in all modes and at any time. The reset pin RES (pin 6) is active high. It is internally pulled down to VSS and therefore does not have to be connected if the function is not required.

As the UZZ9001 has two different voltage supplies, the power-up and power-down reset operates as follows:

1.	Power-Up VDD or VDDA VDD and VDDA	<= 2.8 V >= 4.5 V	reset active reset not active, reset will switch from high to low after a delay of 100 us.
2.	Power-Down VDD or VDDA VDD and VDDA	<= 2.8 V >= 4.4 V	reset active reset not active, device active

If the supply voltage rises, the device is switched into active mode as soon as VDD *AND* VDDA reach the power-up switching level, which lies between 2.8 V and 4.5 V, and the delay of about 100 us has elapsed. In contrast, if the supply voltage at VDD *OR* VDDA goes below the power-down limit, which lies between 2.8 V and 4.4 V, reset becomes active immediately. Due to possible ripples on the supply voltage, a hysteresis of at least 100 mV is implemented between the power-up and power-down switching voltage levels. The following TABLE 11 summarises the specified limits.

TABLE 11: Definitions of switching levels of the build-in reset logic

Parameter	Min	Тур	Max	Unit
Switching voltage for falling VDDA OR VDD	2.8		4.4	V

(9)

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Parameter	Min	Тур	Max	Unit
Switching Hysteresis		0. 3		V
Switching voltage for rising VDDA AND VDD	2.8		4.5	V
Delay for starting the initialization of the UZZ9001 when VDD AND VDDA have risen above the power-up switching level		100		us

5.8 Measurements Dynamics

The UZZ9001 provides an on-chip RC Oscillator that generates the clock for the whole device. Consequently, no external clock supply is required for the measurement system.

The nominal clock frequency of the on-chip oscillator is 4 MHz at room temperature. It varies over temperature. At -40°C, the clock frequency may reduce down to 2.3 MHz. At higher temperatures, however, a frequency up to 5.7 MHz may occur. Consequently, this influences the dynamics of measurements. From the application point of view, two different effects have to be distinguished: The system delay, which means how long it takes until a changed input signal is recognized at the output, and the measurement update rate.

The system delay is mainly caused by the settling time of the low pass decimation filter, which depends on the maximum frequency content (shape) of the input signals and the clock frequency. The following maximum values can be expected for the entire system delay (see TABLE 12):

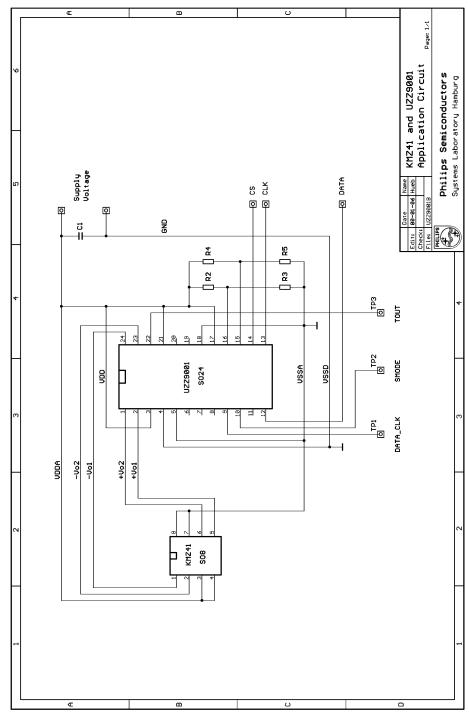
Parameter / Conditions	Min	Тур	Max	Unit
System delay defined as the time passes by until 95% of the final value is reached:				
 Max. signal frequency < 200Hz 			0.6	ms
- Transients (Step response)			1.2	ms
Measurement update rate:				
40°C	0.45			ms
 25°C (room temperature) 		0.26		ms
- 150°C			0.18	ms

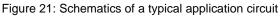
The measurement update rate, however, is directly related to the oscillator frequency. At room temperature, a new value is available every 0.26 ms. When looking at the entire temperature range of the UZZ9001, update rates between 0.45 ms and 0.18 ms are possible (see TABLE 12).

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5.9 Typical Application Circuit

Figure 21 shows a typical application circuit.





6 SYSTEM ACCURACY

6.1 Sensor KMZ41

There are three different errors that may be caused by non-adequate magnetic field arrangements. These are:

- Form deviations of the sensor signals (no sinusoidal shape) and hysteresis of the sensor response if the magnetic field H does not saturate the sensor.
- Form deviations of the sensor signals caused by a non-symmetrical sensor to magnet arrangement (inhomogeneous magnetic field).
- Influence of external magnetic fields influencing the primary field used for measurements.

The influence of external fields can not be described in general as these effects depend on the actual measurement set-up. Therefore this item is not discussed within this paper. The only possibility to get rid of external fields or to limit its impact is to use some kind of a magnetic shielding as discussed in section 4.

In addition to these magnetic effects, there are some non-ideal properties of the KMZ41 sensor affecting the system accuracy. These are discussed in section 7.1.3.

6.1.1 Less Magnetic Field Strength

A complete saturation of the sensor would require the usage of an infinite magnetic field. Consequently, a complete saturation is impossible in practice and errors caused by fewer magnetic fields have to be taken into account. The magnetic field strength, which is proposed in this paper, is a compromise between the remaining error and magnet costs.

Insufficient magnetic field has two effects. The first one is the signal form error caused by a nonsinusoidal shape of the output signals (see Figure 22). Figure 23 shows the shape of the resulting measurement error. Due to its geometrical nature, the maximum and minimum values will always occur at the same locations for every sensor. Maximum values occur at the mechanical angles of 11.25°, 33.75°, 56.25°, 78.75°, 101.25°, 123.75°, 146.25° and 168.25°. No measurement errors occur at 22.5°, 45°, 67.5°, 90°, 112.5°, 135°, 157.5° and 180°.

Figure 24 shows the relation between the magnetic field strength H and the maximum peak error E_{Form} that may occur. At the recommended magnetic field strength of 100 kA/m, the measurement error is less than $E_{Form} = 0.04^{\circ}$ and therefore negligible. The signal form error is reversible and does not depend on the history, as it is the case for hysteresis effects.

Hysteresis effects become visible if the angle turns back and forth over larger angular ranges as shown in Figure 25. The positions where these errors occur depend on the direction of movement. If fields become stronger, the hysteresis zones shrink to smaller areas around the positions 0°, 45°, 90° and 135°. Figure 24 also gives the maximum error caused by hysteresis effects. These are less than the errors caused by the signal form error.

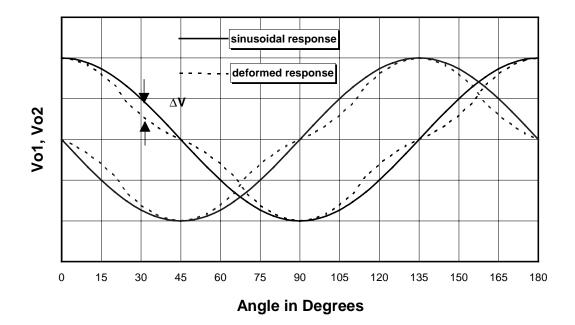
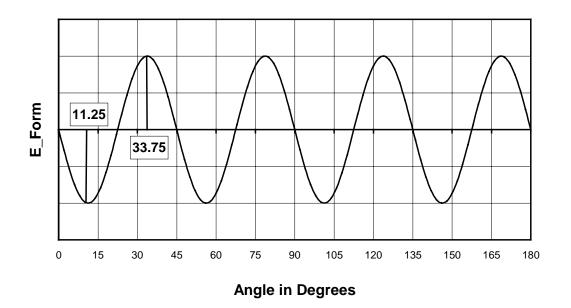
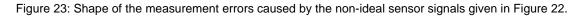


Figure 22: Signal form error of KMZ41 output signals caused by too low magnetic field not saturating the sensor





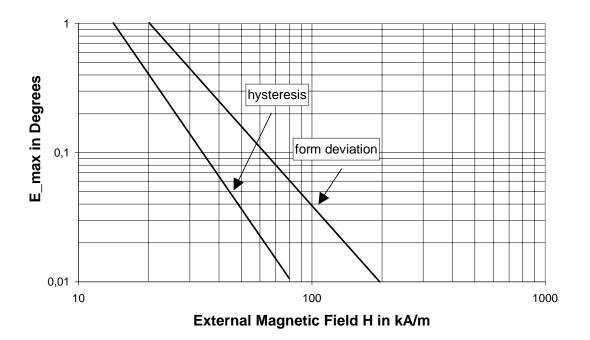


Figure 24: Maximum measurement error caused by signal form error and hysteresis

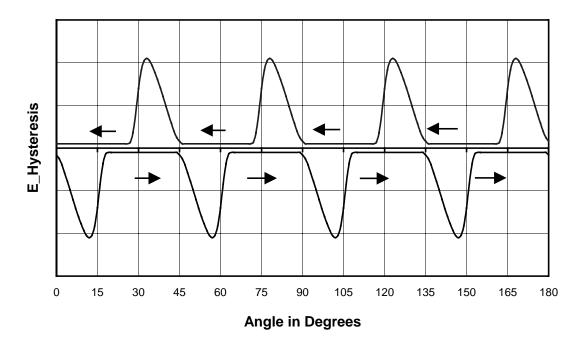


Figure 25: Shape of the measurement error caused by hysteresis

It is obvious that the measurement error caused by signal form errors and hysteresis can be neglected when using a magnetic field around 100 kA/m.

Another argument for using strong magnetic fields is the lower impact of external magnetic fields. This is especially an issue when using an unshielded magnet set-up. Here, even the very small magnetic earth field of about 30 A/m causes measurement errors. To give a rough estimation, an earth field perpendicular to the measurement field of 100 kA/m would cause a maximum error of 0.017°. Ten times this error would occur when operating at 10 kA/m, and this is not negligible.

6.1.2 Effects of Inhomogeneous Magnetic Fields

The sensor signal will get deformed even if sensor and magnet are not precisely aligned, which also may cause measurement errors. The reason for these deformations is that then the sensitive part of the sensor is not completely placed in the homogeneous part of the magnetic field, or, in other words, the relevant part of the magnetic field used for measurements has become inhomogeneous. As the actual angular error resulting from an inhomogeneous field depends on the specific set-up, it can not be calculated in general. However, for the simple block magnet arrangement discussed before, a rule of thumb can be used.

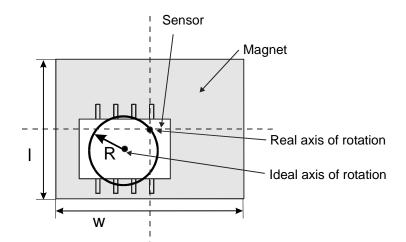


Figure 26: Definition of parameters for calculating the angular error caused by an inhomogeneous field.

Assuming the magnet arrangement depicted in Figure 2, the resulting maximum angular error can be estimated as given in Equation (10):

$$E_{\rm Inhomogenoeus} = C \cdot R^2 \tag{10}$$

with: $C = \frac{320^{\circ}}{(w+l)^2}$ Magnet Constant

- RRadius of the circle in which the centre of the magnet lies (see Figure 26).The midpoint of this circle is identical with the ideal axis of rotation
- *w* Width of the magnet
- *l* Length of the magnet

Note that w and I describe the magnet surface faced to the sensor. For the above mentioned magnets (see Figure 8), w and I are approximately 8 mm and thus $C \approx 1.25^{\circ}/\text{mm}^2$. Consequently, a radius R of 1 mm (the magnet is positioned 1 mm apart from the ideal position) can cause maximum errors up to 1.25°. As a result, small mounting tolerances are strongly recommended when using a simple block magnet arrangement. However, enlarging the magnet will reduce this error at the expense of higher magnet costs.

Please note that this error calculation is only applicable for the block magnet arrangement. When looking at more complex magnetic designs, e.g. the one depicted in Figure 9, a customised solution must be found. Normally, when carefully designing such a complex magnetic circuit, higher mounting tolerances are possible.

Also a non-parallel position of the sensor surface and magnet surface causes errors due to an inhomogeneous magnetic field in the sensitive area of the sensor. But as long as this deviation can be limited to the range of 1° to 2°, the resulting measurement error is negligible. Consequently, the achievable precision regarding parallel mounting should not be a limiting factor.

6.1.3 Non-Ideal Properties of the Components

Due to production scatter, the KMZ41 does not generate ideal output signals but shows some variations in performance. Since continuous improvement is the target of this sensor, please refer to the latest data sheet of the KMZ41 to get current data. In the following sections, the different effects and their impact on system accuracy are described in general.

6.1.3.1 Offset and Offset Drift

The sinusoidal output signals of the KMZ41 may show offsets that limit the accuracy of the system. From the application point of view, the offset of each channel can be subdivided into two parts: a constant portion, which is virtually eliminated by trimming, and a portion that changes with temperature but needs no compensation because it is very small. Note that the temperature dependent portion is zero at the temperature where the sensor system was trimmed. Introducing an offset into the mathematical description of both signals gives:

$$X = X_0 \sin 2\alpha + \Delta x \tag{11}$$

$$Y = Y_o \cos 2\alpha + \Delta y \tag{12}$$

The absolute angular error caused by offsets is also a function of the actual angle. It is calculated as follows:

$$E_{Offset}(\alpha, \Delta x, \Delta y) = \left| \alpha - \frac{1}{2} \arctan\left(\frac{X_0 \sin 2\alpha + \Delta x}{Y_0 \cos 2\alpha + \Delta y} \right) \right|$$
(13)

If both channels have the same offsets ($\Delta x = \Delta y$), the maximum angular error is:

$$E_{Offset Max} = 0.4^{\circ} / \% \text{ Amplitude}$$
(14)

This means that an offset of 1% referred to the amplitude $(X_0 / \Delta x = Y_0 / \Delta y = 1\%)$ results in a maximum angular error of 0.4°. Please note that both signal amplitude and offset vary with temperature. Please also note that the angular positions where these maximum errors occur are not fixed but depend on the constellation of Δx to Δy . As these values change from part to part, locations with less errors can not be determined in general.

If only one channel shows an offset but the other is ideal, the worst case value of Equation (14) is reduced by the factor $1/\sqrt{2}$.

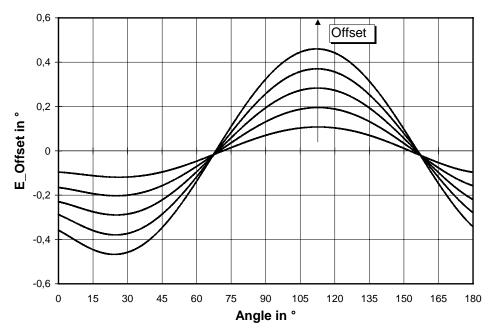


Figure 27: Typical shape of the error curve caused by signal offsets

Figure 27 shows the typical shape of the measurement error over the entire angular range. The error curve has a period of 180° what makes it distinguishable from other error shapes discussed below.

6.1.3.2 Different Signal Amplitudes

Although processed at the same time and on the same silicon substrate, both Wheatstone bridges may show slightly different signal amplitudes. The angular error caused by this effect is as follows:

$$E_{Amplitude}(\alpha, A) = \left| \alpha - \frac{1}{2} \arctan\left(A \frac{\sin 2\alpha}{\cos 2\alpha}\right) \right|$$

$$A = \frac{X_0}{Y_0} \quad \text{Ratio of the signal amplitudes}$$
(15)

with:

Ratio of the signal amplitudes

The maximum error due to differences of signal amplitudes is:

$$E_{Amplitude \max} = 0.158^{\circ} / \%$$
 (16)

This means that differences between the signal amplitudes of 1% will cause a maximum angular error of 0.158°. In contrast to the offset errors, this error function shows a period of 90°. Moreover, the positions where maximum errors occur will not change significantly with A. Figure 28 shows the typical shape of the output curve.

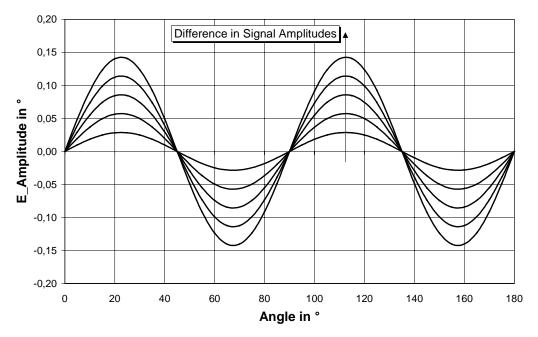


Figure 28: Typical shape of the error curve caused by different signal amplitudes.

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6.1.3.3 Phase Difference between Channels

The last item to be thought of is a phase error between both channels. This means that the phase between signal X and Y is not exactly 90° over the entire angular range. Introducing this error into the mathematical description of the signal gives:

$$X = X_0 \sin(2\alpha + \Delta\beta(\alpha)) \tag{17}$$

$$Y = Y_o \cos 2\alpha \tag{18}$$

Note that the phase shift is a function of the actual angle α and therefore may not be constant over the entire angular range. The resulting angular error can be calculated as follows:

$$E_{Phase}(\alpha, \Delta\beta) = \left| \alpha - \frac{1}{2} \arctan\left(\frac{\sin(2\alpha + \Delta\beta(\alpha))}{\cos 2\alpha} \right) \right|$$
(19)

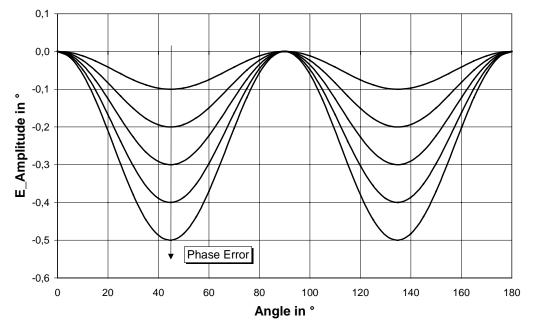


Figure 29: Typical shape of an error curve caused by phase errors.

Assuming a constant phase error, the maximum measurement error that may occur is:

$$E_{Phase Max} = 0.5^{\circ} / ^{\circ}$$
 Phase Shift

(20)

This means that a phase shift of 1° results in a maximum angular error of 0.5°. Figure 29 shows the shape of the corresponding error function.

7.1.4 Discussion of Different Effects

When looking at the different effects discussed before, it makes sense to distinguish between errors that can be omitted when carefully designing a system and others to which the designer has no control.

The errors caused by insufficient magnetic fields are negligible when using a suitable magnet system. Therefore they must only be included in the error budget, if weaker magnets should be used in order to reduce costs. The same argumentation holds with respect to the mechanical mounting tolerances. If accuracy is important, the magnet system can be designed to provide a larger homogeneous area, allowing mounting tolerances without any impact on system accuracy. In turn, when a simple block magnet is used, mounting tolerances can be limited to reasonable values of, for example, 0.1 mm eccentricity or less.

Consequently, only errors caused by offset, different signal amplitudes and phase shift between the two channels should be taken into account. As process scatters cause these errors, it is adequate to use a statistical calculation of the overall error for the KMZ41. This can be formulated mathematically as given in Equation (24):

$$E_{KMZ41_Max} = \sqrt{E_{Offset_Max}^2 + E_{Amplitude_Max}^2 + E_{Phase_Max}^2}$$
(21)

In order to get the overall error for the measurement system the errors caused by the UZZ9001 have to be added to this value.

6.2 Signal Conditioning IC UZZ9001

There are several blocks in the UZZ9001 that may cause errors, e.g. the ADC and the ALU. These errors should not be discussed in detail. An analysis shows that the accuracy of the UZZ9001 is better than 0.35° in any case. This value holds over the entire specified temperature range and at all angular ranges provided.

$$E_{Signal Max} < 0.45^{\circ} \tag{22}$$

This worst case value is true for the 180° angular range of the UZZ9001. In smaller angular ranges, however, the absolute error caused by the DAC becomes smaller because then the whole output voltage range is matched to that smaller range. But as this does not significantly reduce the overall

error of the UZZ9001, for simplicity, the worst case value should be used for error calculations to be on the safe side.

Additionally, the accuracy and stability of the trimming voltage has to be taken into account. An estimate of the remaining offset error after trimming can be determined according to the following procedure (compare with section 5.4):

- 1. Determine the maximum voltage error of the resistor divider used for offset compensation with temperature and over lifetime according to Equation (12).
- 2. Determine the achievable accuracy with the trimming equipment according to Equation (11).
- 3. Add both values to get the remaining offset.

Example:

Assume that the resistor divider guarantees an accuracy better than 0.2 % VDDA with temperature and over lifetime (compare with Table 10). This means that the maximum offset voltage due to this effect would be less than 0.12 mV at 5V supply voltage (see Equation (12)).

Moreover, the measurement and trimming equipment may guarantee a duty cycle between 49.96% and 50.04%. According to Equation (11), the remaining offset voltage would be less than 0.1 mV at 5V supply voltage. Consequently, the DC offset voltage caused by non-ideal trimming is:

$$U_{Offset Trim} = 0.12 \text{ mV} + 0.1 \text{ mV} = 0.22 \text{ mV}$$
 (23)

This resulting angular error E_{Trim} has to be added to the value resulting from offset drift of the KMZ41. Consequently, the overall error budget for the UZZ9001 is:

$$E_{UZZ9000_Max} = \sqrt{E_{Signal_Max}^2 + E_{Trim}^2}$$
(24)

6.3 Application Example for Error Calculation

The following example serves to demonstrate a way to calculate the minimum accuracy that can be expected from a MR based measurement system under certain system constraints. The component specific data are taken from the current specification of the KMZ41 and UZZ9001 (see references (1) and (2)). As these devices are targets to continuous improvement, please refer to the latest data sheets to get data presently valid.

The system data assumed and the component data used are as follows:

 Temperature range required for the system: 	-40°C to 85°C
Temperature while trimming:	25°C
 Maximum phase error between channels: 	0.5°
 Maximum error of amplitude synchronism (k): 	0.5 %
Offset Drift (TCVoffset):	2 µV / V / K
Constant offset due to non-ideal trimming:	0.2 mV
Supply voltage:	5 V
Signal amplitude KMZ41:	78 mV @ 25°C
• Temperature coefficient of peak voltage (TCVpeak):	-0.31 % / K

The temperature during trimming is 25°C and therefore lies in the middle of the required operating temperature range. Consequently, the maximum change of temperature referred to this trimming temperature is about 60°C.

Nevertheless the upper limit of the operating temperature range of 85°C is more critical because the signal amplitude decreases with higher temperatures and therefore the percentage of offset to be taken into account increases. With the given data, the maximum offset voltage at 85°C is:

$$U_{Offset_Max} = 2 \ \mu V/V/^{\circ}C \cdot 5V \cdot 60 \ ^{\circ}C = 0.60 \ mV$$
 (25)

The amplitude of the signal at 85°C is 63.5 mV which is calculated using Equation (6) (TCVpeak = -0.31 % / K). As a result, the maximum offset caused by offset drift is:

$$Offset_{Max} = \frac{0.60 \text{ mV}}{63.5 \text{ mV}} 100\% = 0.94\%$$
(26)

The graph in Figure 30 shows the results of this calculation at other temperatures. For example, the offset drift to be taken into account at 125°C would be 1.7 %. At the maximum temperature of 150°C, 2.6 % offset may occur.

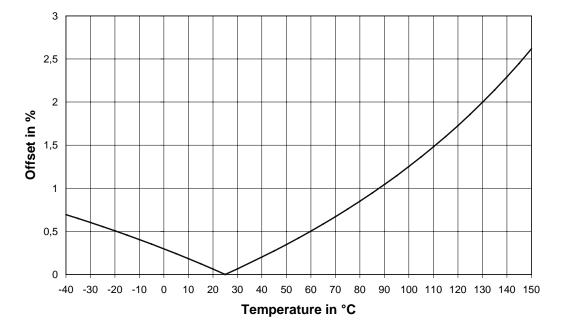


Figure 30: Offset drift at different maximum temperatures assuming the data defined in the text.

The maximum angular error caused by this offset drift can be calculated according to Equation (17). An offset of 0.94% corresponds to a maximum angular error of

$$E_{Offset_Max} = 0.94\% \cdot 0.4^{\circ} / \% = 0.38^{\circ}.$$
⁽²⁷⁾

In addition to offset drift, the trim error adds another portion. With the given remaining offset voltage of 0.2 mV after trimming, the evaluation of Equation (17) and Equation (29) results in:

$$E_{Trim} = \frac{0.2 \text{ mV}}{63.5 \text{ mV}} \cdot 0.4^{\circ} / \% = 0.13^{\circ}$$
⁽²⁸⁾

Similarly, the maximum phase error and the maximum amplitude error can be calculated according to Equation (19) and Equation (23). The results are:

$$E_{Amplitude_Max} = 0.5 \% \cdot 0.158^{\circ} / \% = 0.08^{\circ}$$
⁽²⁹⁾

$$E_{Phase Max} = 0.5^{\circ} \cdot 0.5^{\circ} / {}^{\circ} = 0.25^{\circ}$$
(30)

This gives an overall error of

$$E_{Max} = \sqrt{E_{Offset_Max}^2 + E_{Trim}^2 + E_{Phase_Max}^2 + E_{Amplitude_Max}^2 + E_{Signal_Max}^2}$$

= $\sqrt{0.38^2 + 0.13^2 + 0.25^2 + 0.08^2 + 0.35^2} \circ = 0.59^\circ$ (31)

As a result, an accuracy better than 0.6° can be expected under the given constraints.

Please note that due to the input of 3-Sigma values, this result is a 3-Sigma value also and thus typical accuracy will be significantly higher than calculated here. When using the 180° angular range, the relative error would be less than 0.4 %.

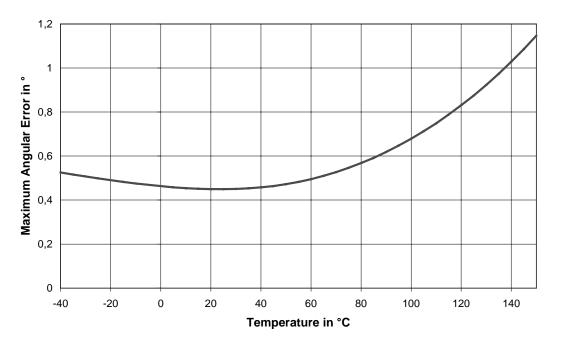


Figure 31: Maximum absolute angular error over temperature assuming the system data given in the example described in the text. The graph shows 3-Sigma values.

Similar calculations can be carried out for other temperature ranges. The result is shown in Figure 31. At 150°C, for example, a maximum error of 1.2° may occur. Again, this is a 3-Sigma value and therefore typical accuracy would be much better than calculated here.

The error $E_{_{System}}$ describes the angle error of the hole measuring system. Therefore, the errors $E_{_{inhomogenoeus}}$ and $E_{_{Form}}$ must be included (section 6.1.2). The overall error $E_{_{System}}$ can be calculated as follows:

$$E_{System} = \sqrt{E_{Max}^2 + E_{Inhomogenoeus}^2 + E_{Form}^2}$$
(32)

The error $E_{inhomogeneous}$ has very often the highest component in the error calculation. This means the effects of inhomogeneous magnetic fields are resulting in high angle errors (see section 6.1.2). Therefore small mounting tolerances are strongly recommend when using a simple block magnet arrangement (see Figure 2). Lower angle errors at higher mounting tolerances are expected with magnetic arrangements shown in section 4.4. An application specific solution must found between system accuracy and system costs.

A measured angle error $E_{_{System}}$ is given in Figure 32. It shows that the angle error can be lower than 0.25° by a proper magnetic arrangement.

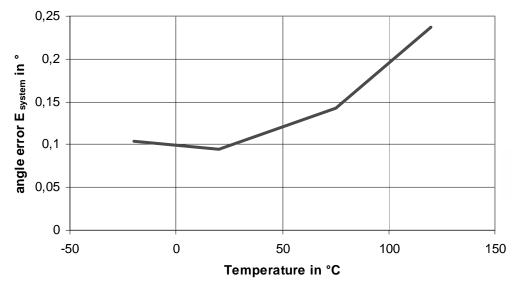


Figure 32: Measured angle error E_{system} for a typical set-up

7 REFERENCES

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